NCE15P25JK

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE15P25JK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

● V_{DS} =-150V,I_D =-25A

 $R_{DS(ON)}$ <135m Ω @ V_{GS} =-10V (Typ.=120mR)

 $R_{DS(ON)}$ <160m Ω @ V_{GS} =-4.5V (Typ.=131mR)

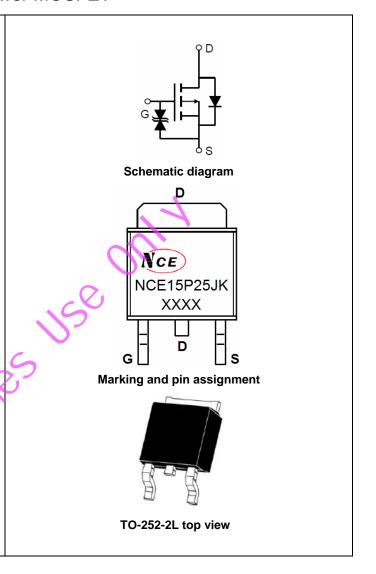
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

Application

Portable equipment and battery powered systems

100% UIS TESTED!

100% ΔVds TESTED



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE15P25JK	NCE15P25JK	TO-252-2L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-150	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	-25	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	-17	Α
Pulsed Drain Current	I _{DM}	-140	А
Maximum Power Dissipation	P _D	160	W
Derating factor		1.3	W/℃
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}\!\mathbb{C}$



http://www.ncepower.com

NCE15P25JK

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	R _{θJc}	0.8	°C/W	1
-----------------------------------------------	------------------	-----	------	---

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-145	-155	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-145V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±10	μΑ
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.5	-1.9	-3	V
Drain-Source On-State Resistance	В	V _{GS} =-10V, I _D =-20A	1	120	135	mΩ
Diani-Source On-State Resistance	$R_{DS(ON)}$	V _{GS} =-4.5V, I _D =-20A	-	131	160	
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-20A	5	-	-	S
Dynamic Characteristics (Note4)		0				
Input Capacitance	C _{lss}	V - 75 (11) -0V	-	7650	-	PF
Output Capacitance	Coss	V _{DS} =-75V,V _{GS} =0V, F=1.0MHz	-	148	-	PF
Reverse Transfer Capacitance	C _{rss}	r-1.0ivii iz	-	131	-	PF
Switching Characteristics (Note 4)		3				
Turn-on Delay Time	t _{d(on)}	NO .	-	17	-	nS
Turn-on Rise Time	t _r	V _{DD} =-75V,I _D =-20A	-	80	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =9.1 Ω	-	45	-	nS
Turn-Off Fall Time	t _f		-	65	-	nS
Total Gate Charge	Q_g	V _{DS} =-75V,I _D =-20A,	-	137	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS} = 75V, I_{D} = 20A,$ $V_{GS} = -10V$	-	25	-	nC
Gate-Drain Charge	Q_{gd}	VGS10V	-	28	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-25A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-25	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =-25A	-	90	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	105	-	nC

Notes:

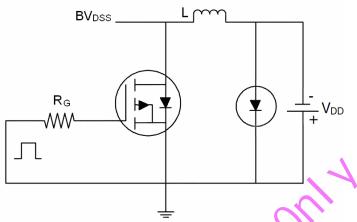
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=-75V,V_G=-10V,L=0.5mH,Rg=25 Ω



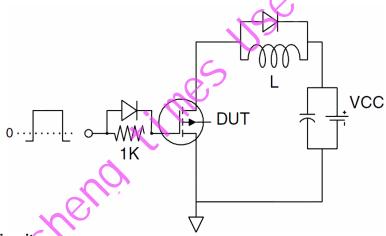
NCE15P25JK

Test Circuit

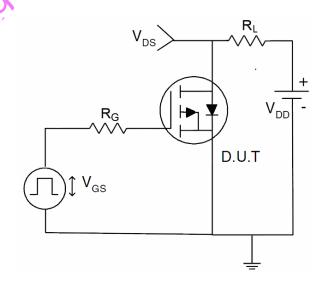
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Pb Free Product



Typical Electrical and Thermal Characteristics (Curves)

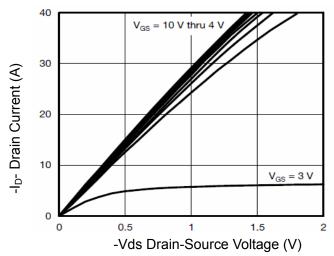


Figure 1 Output Characteristics

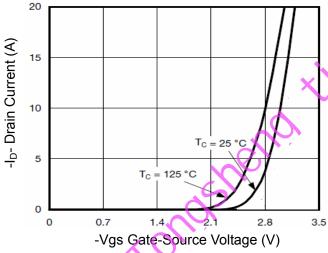
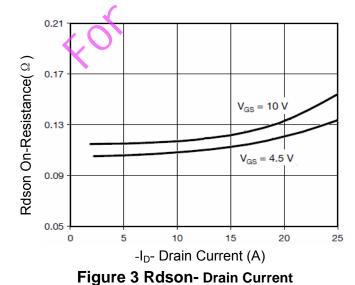


Figure 2 Transfer Characteristics



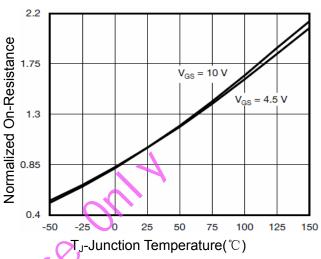


Figure 4 Rdson-JunctionTemperature

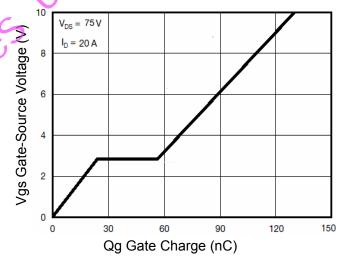


Figure 5 Gate Charge

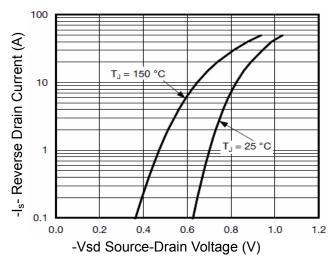
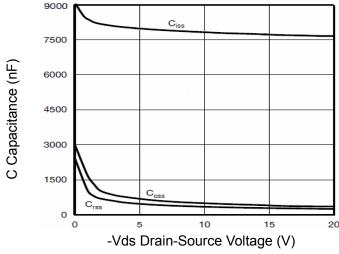


Figure 6 Source- Drain Diode Forward

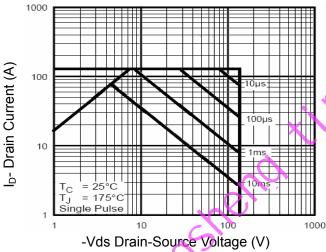




(V) 30 20 25 50 75 100 125 150 175 T_C Case Temperature(°C)

Figure 7 Capacitance vs Vds

Figure 9 Drain Current vs Case Temperature



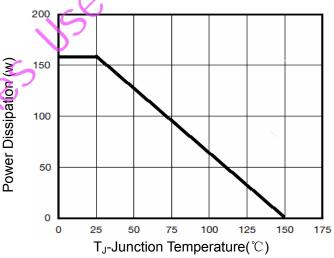


Figure 8 Safe Operation Area

Figure 10 Power De-rating

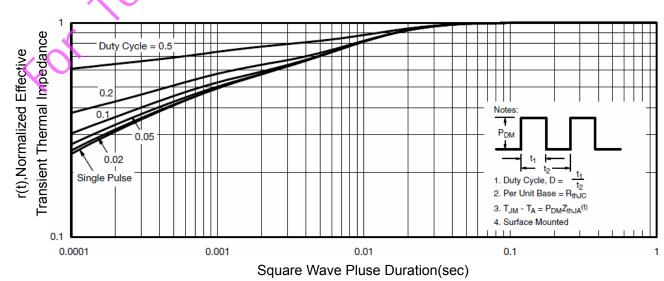
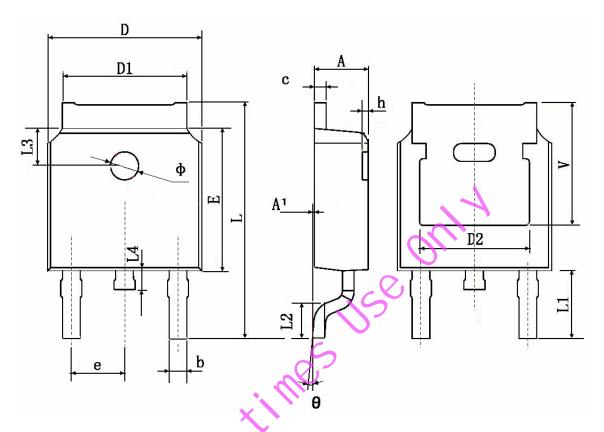


Figure 11 Normalized Maximum Transient Thermal Impedance

Pb Free Product



TO-252 Package Information



Comple ed	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D 🗸	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2 🌈	4.83	4.83 TYP. 0.190 TYP.			
∠ €	6.000	6.200	0.236	0.244	
e	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	TYP.	0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



ortoni

http://www.ncepower.com

NCE15P25JK

Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.